

## R-C Thermal Model Parameters

### DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/tank and Cauer/filter configurations are included. When implemented in P-SPICE, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in application note AN609, "Thermal Simulation of Power MOSFETs on the P-SPICE Platform".

### R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RT1	60.6226	N/A	9.0636
RT2	16.9468	N/A	2.7529
RT3	61.1716	N/A	7.5912
RT4	25.7992	N/A	30.5800
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	1.4484	N/A	4.1442m
CT2	270.6257m	N/A	279.3391u
CT3	6.2137m	N/A	235.0682m
CT4	1.1200m	N/A	12.3991m

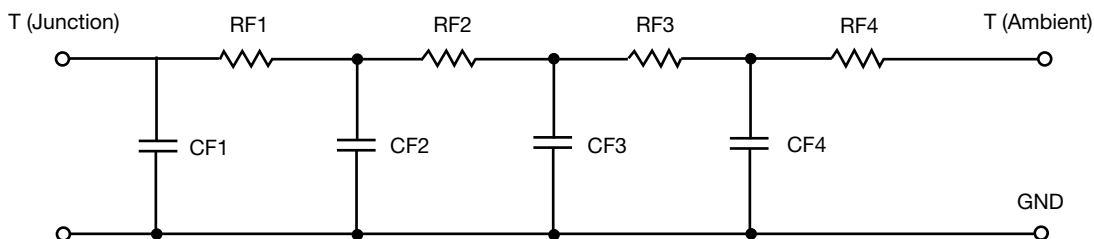
#### Note

N/A indicates not applicable

*This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.*



**R-C THERMAL MODEL FOR FILTER CONFIGURATION**



<b>R-C VALUES FOR FILTER CONFIGURATION</b>			
<b>THERMAL RESISTANCE (°C/W)</b>			
<b>Junction to</b>	<b>Ambient</b>	<b>Case</b>	<b>Foot</b>
RF1	13.2458	N/A	4.4849
RF2	47.7806	N/A	19.2482
RF3	39.0015	N/A	23.1495
RF4	63.8436	N/A	3.4892
<b>THERMAL CAPACITANCE (Joules/°C)</b>			
<b>Junction to</b>	<b>Ambient</b>	<b>Case</b>	<b>Foot</b>
CF1	462.9800u	N/A	389.9940u
CF2	2.0270m	N/A	3.7588m
CF3	15.7873m	N/A	14.7082m
CF4	1.1631	N/A	861.0071m

**Note**

N/A indicates not applicable

